



### **40V N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

40 A

#### **Features**

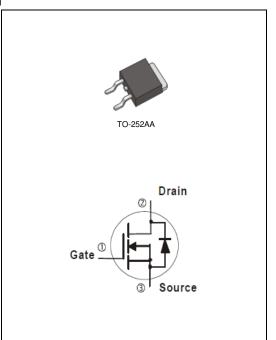
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@20A<12m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@10A<17m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: TO-252AA Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Weight: 0.0104 ounces, 0.297grams



# $\textbf{Maximum Ratings and Thermal Characteristics} \; (T_{A} = 25 ^{\circ} \text{C unless otherwise noted})$

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	40	A	
	T <sub>C</sub> =100°C		25		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	$I_{DM}$	120		
Power Dissipation	T <sub>C</sub> =25°C	PD	43.2	147	
	T <sub>C</sub> =100°C		21.6	W	
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	10	^	
	T <sub>A</sub> =70°C		8	Α	
Power Dissipation	T <sub>A</sub> =25°C	Po	2.4	W	
	T <sub>A</sub> =70°C		1.6		
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	3.47	°C/W	
	Junction to Ambient	$R_{ heta JA}$	62.5		

• Limited only By Maximum Junction Temperature





## **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250uA	40	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$		1	1.7	2.5		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}=10V,I_D=20A$	-	10	12	mΩ	
		$V_{GS}$ =4.5 $V$ , $I_{D}$ =10 $A$	-	13	17		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =40V, $V_{GS}$ =0V	-	-	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	$Q_{g}$	V <sub>DS</sub> =20V, I <sub>D</sub> =10A, V <sub>GS</sub> =4.5V (Note 2,3)	-	10	-	nC	
Gate-Source Charge	$Q_{gs}$		-	3.5	-		
Gate-Drain Charge	$Q_{gd}$		-	3.6	-		
Input Capacitance	Ciss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1040	-	pF	
Output Capacitance	Coss		-	117	-		
Reverse Transfer Capacitance	Crss	I=I.UIVITZ	-	84	-		
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DS}{=}20V, I_{D}{=}1A,$ $V_{GS}{=}10V, \ R_{G}{=}6\Omega$ (Note 2,3)	-	9.4	-		
Turn-On Rise Time	t <sub>r</sub>		-	19	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>		-	66	-		
Turn-Off Fall Time	t <sub>f</sub>		-	67	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	,				40	Α	
Diode Forward Current	I <sub>S</sub>		-	-	40	A	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.7	1	V	

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

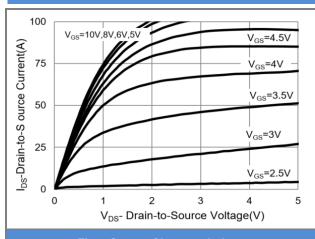
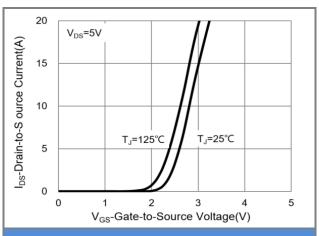


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

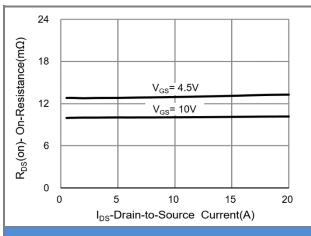


Fig.3 On-Resistance vs. Drain Current

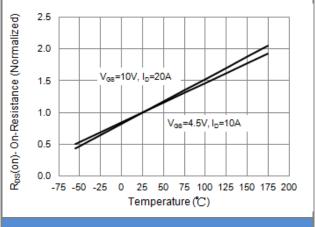


Fig.4 On-Resistance vs. Junction temperature

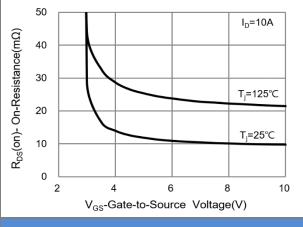


Fig.5 On-Resistance Variation with V<sub>GS</sub>

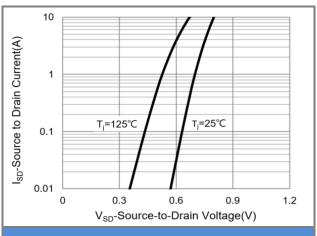


Fig.6 Source-Drain Diode Forward Voltage





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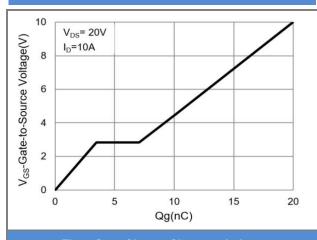


Fig.7 Gate-Charge Characteristics

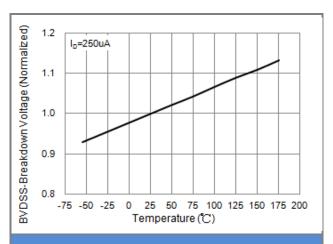


Fig.8 Breakdown Voltage Variation vs. Temperature

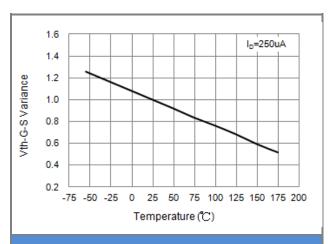


Fig.9 Threshold Voltage Variation with Temperature

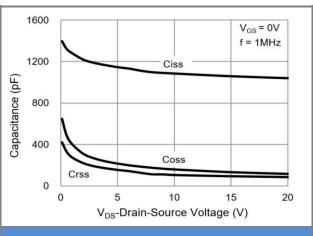


Fig.10 Capacitance vs. Drain-Source Voltage

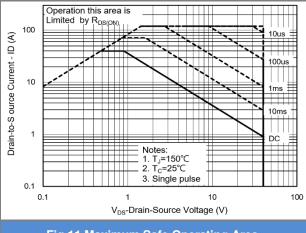
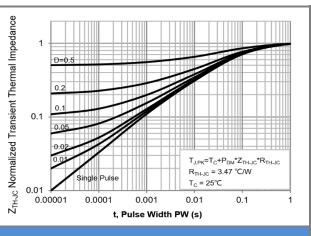


Fig.11 Maximum Safe Operating Area



**Fig.12 Normalized Transient Thermal Impedance** 

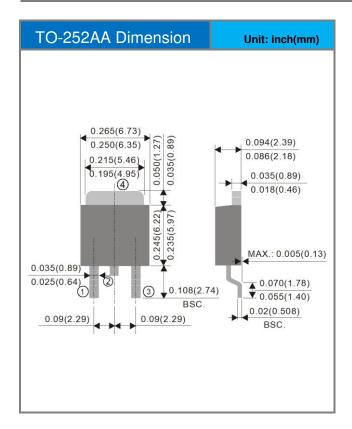


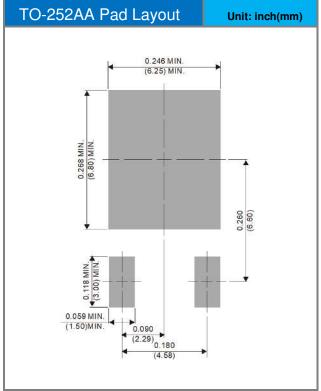


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD40N04-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D40N04	Halogen free

### **Packaging Information & Mounting Pad Layout**









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